



Gallium Arsenide CATV Amplifier Module

Features

- Specified for 79-, 112- and 132-Channel Loading
- Excellent Distortion Performance
- Built-in Input Diode Protection
- GaAs FET Transistor Technology
- Unconditionally Stable Under All Load Conditions
- Improved Ruggedness

Applications

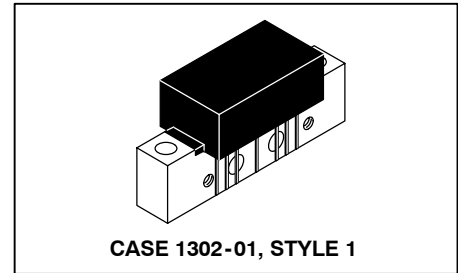
- CATV Systems Operating in the 40 to 870 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Output Stage Amplifier on Applications Requiring Low Power Dissipation and High Output Performance
- Driver Amplifier in Linear General Purpose Applications

Description

- 24 Vdc Supply, 40 to 870 MHz, CATV GaAs Forward Amplifier Module
- Replaced MHW9186A. There are no form, fit or function changes with this part replacement.
- RoHS Compliant

MHW9186AN

**870 MHz
18.5 dB GAIN
132-CHANNEL
GaAs CATV AMPLIFIER MODULE**



ARCHIVE INFORMATION

ARCHIVE INFORMATION

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V_{in}	+65	dBmV
DC Supply Voltage	V_{CC}	+26	Vdc
Operating Case Temperature Range	T_C	-20 to +100	°C
Storage Temperature Range	T_{stg}	-40 to +100	°C

Table 2. ESD Maximum Ratings

Rating	Input Value	Output Value	Unit
Surge Voltage per IEC 1000-4-5	300	300	V
Human Body Model per Mil. Std. 1686	2	2	kV

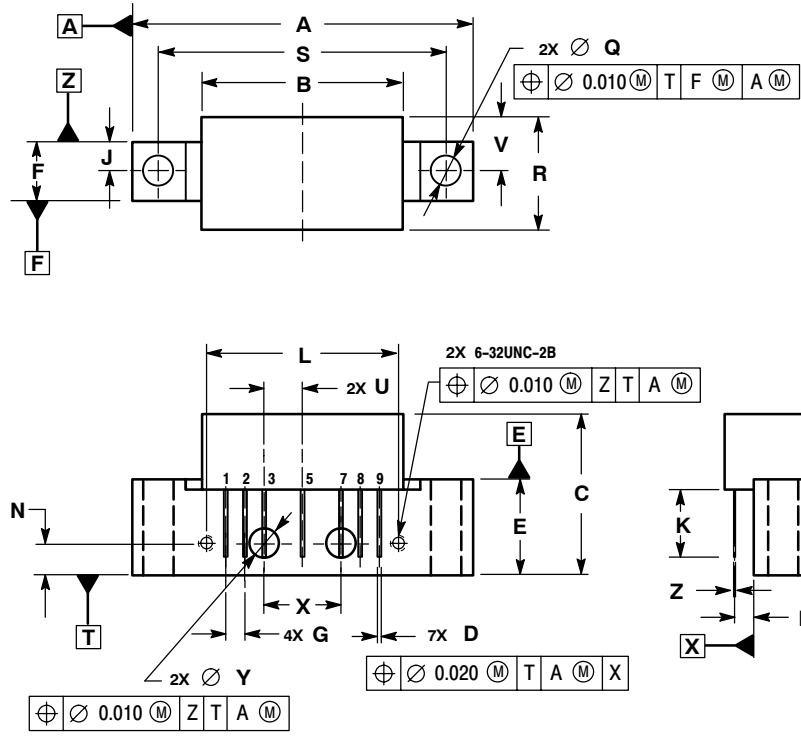
Table 3. Electrical Characteristics ($V_{CC} = 24$ Vdc, $T_C = +30^\circ\text{C}$, 75 Ω system unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Frequency Range	BW	40	—	870	MHz
Power Gain 870 MHz	G_p	18	18.5	19.5	dB
Slope 40-870 MHz	S	0.1	0.6	1.2	dB
Gain Flatness (40-870 MHz, Peak-to-Valley)	G_F	—	0.3	0.8	dB
Return Loss — Input ($Z_o = 75$ Ohms)	IRL	20 19 18	— — —	— — —	dB
Return Loss — Output ($Z_o = 75$ Ohms)	ORL	20 19 18	— — —	— — —	dB

Table 3. Electrical Characteristics ($V_{CC} = 24$ Vdc, $T_C = +30^\circ\text{C}$, 75 Ω system unless otherwise noted) (continued)

Characteristic		Symbol	Min	Typ	Max	Unit
Composite Second Order						dBc
($V_{out} = +44$ dBmV/ch., Worst Case)	132-Channel FLAT	CSO_{132}	—	-67	-60	
($V_{out} = +46$ dBmV/ch., Worst Case)	112-Channel FLAT	CSO_{112}	—	-65	-61	
($V_{out} = +48$ dBmV/ch., Worst Case)	79-Channel FLAT	CSO_{79}	—	-72	-64	
Cross Modulation Distortion @ Ch 2						dBc
($V_{out} = +44$ dBmV/ch., FM = 55 MHz)	132-Channel FLAT	XMD_{132}	—	-58	-52	
($V_{out} = +46$ dBmV/ch., FM = 55 MHz)	112-Channel FLAT	XMD_{112}	—	-58	-52	
($V_{out} = +48$ dBmV/ch., FM = 55 MHz)	79-Channel FLAT	XMD_{79}	—	-58	-52	
Composite Triple Beat						dBc
($V_{out} = +44$ dBmV/ch., Worst Case)	132-Channel FLAT	CTB_{132}	—	-62	-58	
($V_{out} = +46$ dBmV/ch., Worst Case)	112-Channel FLAT	CTB_{112}	—	-61	-58	
($V_{out} = +48$ dBmV/ch., Worst Case)	79-Channel FLAT	CTB_{79}	—	-64	-60	
Noise Figure	50 MHz	NF	—	4.6	6.0	dB
	870 MHz		—	3.7	6.0	
DC Current ($V_{DC} = 24$ V, $T_C = -20^\circ$ to $+100^\circ\text{C}$)		I_{DC}	230	250	265	mA

PACKAGE DIMENSIONS



NOTES:
 1. DIMENSIONS ARE IN INCHES.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	---	1.775	---	45.085
B	---	1.085	---	27.559
C	---	0.840	---	21.336
D	0.015	0.021	0.381	0.533
E	0.465	0.510	11.811	12.954
F	0.300	0.325	7.62	8.255
G	0.100 BSC		2.540 BSC	
J	0.156 BSC		3.962 BSC	
K	0.315	0.355	8.001	9.017
L	1.000 BSC		25.400 BSC	
N	0.165 BSC		4.191 BSC	
P	0.100 BSC		2.540 BSC	
Q	0.148	0.168	3.759	4.267
R	---	0.600	---	15.24
S	---	1.500 BSC	---	38.100 BSC
U	0.200 BSC		5.080 BSC	
V	---	0.250	---	6.350
W	0.435	---	11.049	---
X	0.400 BSC		10.160 BSC	
Y	0.152	0.163	3.861	4.140
Z	0.009	0.011	0.229	0.279

STYLE 1:
 PIN 1. RF INPUT
 2. GROUND
 3. GROUND
 4. DELETED
 5. VDC
 6. DELETED
 7. GROUND
 8. GROUND
 9. RF OUTPUT

**CASE 1302-01
 ISSUE E**

How to Reach Us:

Home Page:
www.freescale.com

E-mail:
support@freescale.com

USA/Europe or Locations Not Listed:
Freescale Semiconductor
Technical Information Center, CH370
1300 N. Alma School Road
Chandler, Arizona 85224
+1-800-521-6274 or +1-480-768-2130
support@freescale.com

Europe, Middle East, and Africa:
Freescale Halbleiter Deutschland GmbH
Technical Information Center
Schatzbogen 7
81829 Muenchen, Germany
+44 1296 380 456 (English)
+46 8 52200080 (English)
+49 89 92103 559 (German)
+33 1 69 35 48 48 (French)
support@freescale.com

Japan:
Freescale Semiconductor Japan Ltd.
Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku,
Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:
Freescale Semiconductor Hong Kong Ltd.
Technical Information Center
2 Dai King Street
Tai Po Industrial Estate
Tai Po, N.T., Hong Kong
+800 2666 8080
support.asia@freescale.com

For Literature Requests Only:
Freescale Semiconductor Literature Distribution Center
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